Observation of ionic Coulomb blockade in nanopores

Jiandong Feng^{1*}, Ke Liu¹, Michael Graf¹, Dumitru Dumcenco², Andras Kis², Massimiliano Di Ventra³ and Aleksandra Radenovic^{1*}

Emergent behaviour from electron-transport properties is routinely observed in systems with dimensions approaching the nanoscale¹. However, analogous mesoscopic behaviour resulting from ionic transport has so far not been observed, most probably because of bottlenecks in the controlled fabrication of subnanometre nanopores for use in nanofluidics. Here, we report measurements of ionic transport through a single subnanometre pore junction, and the observation of ionic Coulomb blockade: the ionic counterpart of the electronic Coulomb blockade observed for quantum dots. Our findings demonstrate that nanoscopic, atomically thin pores allow for the exploration of phenomena in ionic transport, and suggest that nanopores may also further our understanding of transport through biological ion channels.

Electrical transport through single molecules has attracted considerable attention² owing to the possibility of using individual molecules as electronic components³. The first generation of single-molecule electrical measurements was realized by probing transport in single quantum dots, carbon nanotubes, C₆₀ molecules and DNA molecules using microfabricated structures, mechanically formed molecular junctions and scanning probe microscopies⁴. Such ultra-small platforms offer an ideal toolbox for probing electrons one at a time through the individual molecules, enabling direct observation of single-electron phenomena, such as Coulomb blockade, or the Kondo effect⁵ that have substantially contributed to our understanding of fundamental quantum physics and might lead to the realization of diverse quantum devices.

Analogous mesoscopic phenomena have also been predicted for ionic transport through narrow channels when they approach the dimensions of the hydration layers formed around each ion^{6,7}. At very low densities one should then observe single-particle step-like conductance owing to the breaking of hydration layers as a function of channel radius^{6,7}, whereas at larger densities ion–ion interactions should lead to the equivalent of Coulomb blockade when the channel has the appropriate capacitance^{6,8}. However, owing to the requirement of controlled sub-nm channels, these phenomena have not been observed so far for ionic transport in nanofluidic systems⁹. Instead, ionic transport through nanochannels/nanopores typically exhibits ohmic behaviour. Voltage-activated nonlinear ion transport was also observed in various systems, such as hydrophobic wetting and ion dehydration^{10,11}.

Here, we report for the first time the experimental observation of single-ion transport through the ionic junction of a sub-nm MoS_2 pore. We observe that the current–voltage characteristics of ionic transport show nonlinear behaviour that exhibits a voltage gap at low applied bias. We suggest a single-ion transport mechanism

based on single-ion charging, where the combination of Coulomb blockade and dehydration determines the ion transport through the sub-nm pore. Our observation is in a good agreement with predictions obtained for both solid-state pores⁶ and a biological ion channel that has a similar geometry to the sub-nm solid-state nanopore reported here⁸, and it is reminiscent of the same phenomenon observed in electronic transport through quantum dots.

The experiments are conducted in a typical configuration where the two chambers with ionic solutions are separated by a single nanopore in a single-layer molybdenum disulfide (MoS₂) membrane¹² and biased by a pair of Ag/AgCl electrodes, as described in Fig. 1a. The sub-nm nanopores used in this study are produced in a single-layer MoS2 membrane either by our recently reported atomic-scale nanopore fabrication technique using controlled electrochemical reaction or by electron irradiation within a Cs-corrected transmission electron microscope, as described elsewhere 12,13. These techniques result in the opening of pores with diameters down to 0.3 nm. From the plethora of twodimensional materials we have chosen 0.65-nm-thick single-layer MoS₂ (ref. 12), owing to the fact that it allows better control during nanopore fabrication^{12,13} and nanopores that exhibit better water transport when compared to graphene¹⁴. Fig. 1b shows an image of pristine single-layer MoS₂, a sulfur vacancy that acts as an initial site for nanopore formation during electrochemical reaction (Fig. 1c) and a 0.6-nm-diameter nanopore (Fig. 1d). For measurements in this work, we have mostly used pores fabricated using controlled electrochemical reaction¹³. The electrical characteristics of the pore are then determined by acquiring their current-voltage (I-V)response in aqueous solutions of salts.

All I-V measurements are performed at room temperature. Fig. 2a shows typical I-V characteristics of a 0.6-nm pore in potassium chloride (KCl) aqueous solutions with a range of ionic strengths (10 mM-4 M). The curves exhibit a striking nonlinear behaviour, with an apparent gap of \sim 400 mV. At small voltages, the current is suppressed. When the bias voltage exceeds the threshold value, the current starts to increase more strongly. Corresponding differential conductance (dI/dV) plots are shown in Fig. 2b. Zero conductance is found in the gap region, as well as a conductance that increases with applied bias. This phenomenon differs largely from conventional ion transport through nanopores with larger sizes¹⁵, which can be described using classical Poisson-Nernst-Planck equations¹⁶. Representative I-V curves from larger MoS₂ pores (d > 1 nm) are shown in Supplementary Fig. 1, exhibiting linear, ohmic responses. The response of another 0.6-nm MoS₂ nanopore to different ion types is shown in Fig. 3. All tested metal ion types (K+, Na+, Li+, Ca2+, Mg2+) exhibit nonlinearity in their

¹Laboratory of Nanoscale Biology, Institute of Bioengineering, School of Engineering, EPFL, 1015 Lausanne, Switzerland. ²Laboratory of Nanoscale Electronics and Structures, Institute of Electrical Engineering, School of Engineering, EPFL, 1015 Lausanne, Switzerland. ³Department of Physics, University of California, San Diego, La Jolla, California 92093, USA. *e-mail: jiandong.feng@epfl.ch; aleksandra.radenovic@epfl.ch

LETTERS

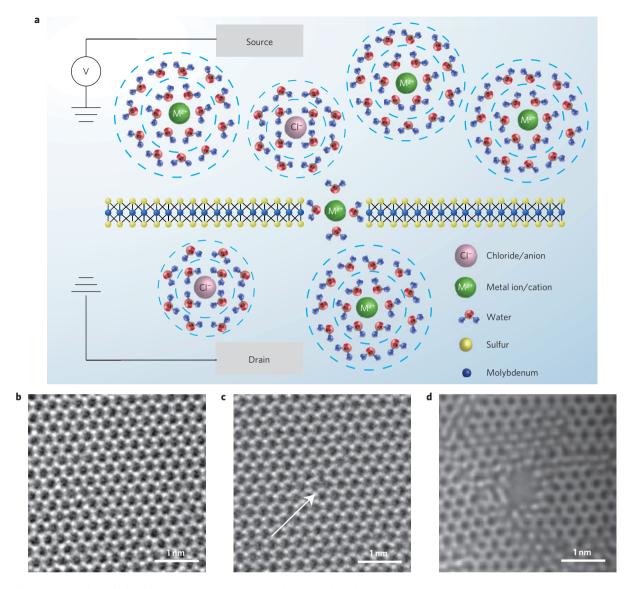


Figure 1 | **Ion transport through the sub-nm nanopore junction. a**, Schematics of single-ion transport through a sub-nm MoS_2 nanopore. **b**, Aberration-corrected transmission electron microscopy (TEM) image of a single-layer MoS_2 membrane without a pore. **c**, Aberration-corrected TEM image of a single-atom vacancy (marked by arrow) in a single-layer MoS_2 membrane. **d**, Aberration-corrected TEM image of a 0.6-nm-diameter MoS_2 nanopore.

I-V characteristics (Fig. 3a), with different gap sizes for different ions and a strong dependence on the valence (referring to the differential conductance shown in Fig. 3b). Compared to other ions, the I-V characteristic of the divalent ions $\mathrm{Mg^{2+}}$ and $\mathrm{Ca^{2+}}$ shows a more suppressed current for positive voltages than the monovalent ions $\mathrm{K^{+}}$, $\mathrm{Na^{+}}$ and $\mathrm{Li^{+}}$. The hydrophilic nature of $\mathrm{MoS_{2}}$ pores owing to the Mo-rich pore surface and the pore wetting procedure we use, which involves soaking nanopores in an ethanol/water mixture, eliminates the possibility that nonlinearity originates from hydrophobic effects 10,17 .

To understand the nature of the ionic transport measurements, we first used an analogy to electric transport through a quantum dot/single-molecule system⁴, shown in Supplementary Fig. 2. Here, the small capacitance of a system weakly coupled to electrodes through tunnel junctions gives rise to Coulomb blockade^{18,19}. In the schematics in Fig. 2c,d, and the energy diagrams in Fig. 2e, we attempt to define the 'electronic structure' of the single-ion channel device and employ the Coulomb blockade theory for ionic transport. In addition to a resistance, a nanopore junction also has a capacitance. A charging energy then needs to be overcome when

the capacitance of the system is small enough such that many-body ion–ion interaction effects dominate. Therefore, the suppressed conductance in the subthreshold regime is a consequence of the finite energy required to add a charge carrier (ion) to the pore. Referring to the Coulomb blockade model²⁰ this addition energy (Δ_{N+1}) is given by

$$\Delta_{N+1} = \mu_{N+1} - \mu_N = U + \Delta E \tag{1}$$

where μ_N is the electrochemical potential of an N-ion system, U is the Coulomb interaction energy between two ions in the pore and ΔE is the electronic excitation energy.

The ionic Coulomb interaction can be estimated using the electrostatic self-energy²¹ by considering a one-dimensional Coulomb gas model of ions²². Following the ionic Coulomb blockade model developed by Kaufman *et al.*⁸, the Coulomb gap can be obtained as a function of pore geometry and ion valence^{8,22},

$$U = \frac{z^2 e^2}{2C} = \frac{1}{4\pi\varepsilon_0} \frac{z^2 e^2 L}{2\varepsilon_W r^2}$$
 (2)

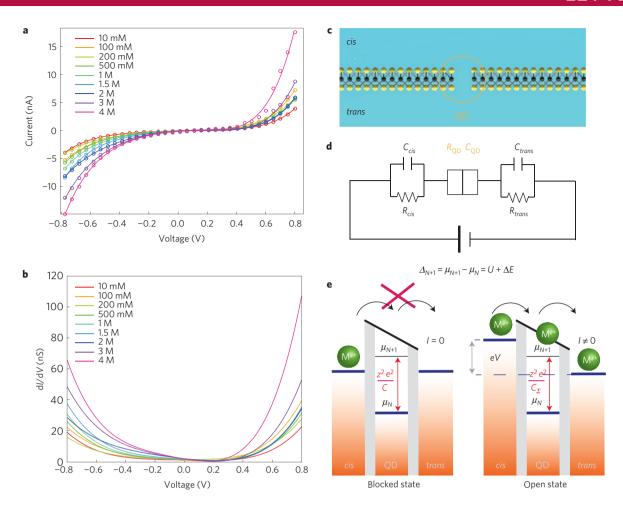


Figure 2 | **Current-voltage characteristics** (I–V) of a 0.6-nm MoS $_2$ nanopore in a potassium chloride aqueous solution (KCl). a, I–V curves acquired under different ion concentrations. b, Differential conductance (dI/dV) of a 0.6-nm MoS $_2$ in KCl solutions of different molarities. c, Illustration of a single-ion junction in the form of small-diameter nanopores in the two-dimensional material MoS $_2$. An analogy to quantum dot, QD, is used to describe the nanopore ion junction. d, Corresponding equivalent circuit for the system shown in c. C, capacitance; R, resistance. e, Equivalent energy-level diagram for ionic Coulomb blockade due to single-ion charging in nanopores. With the sub-nm pore configuration presented, this charging energy is much larger than the thermal energy (k_BT), otherwise the ion will be able to pass by means of thermal excitation. Ionic conduction is suppressed (blocked state, left) when the applied bias (eV) is below the charging energy. A build-up in voltage above the charging energy allows conduction (open state, right) with a strong dependence on ion valence number z.

where *e* is the elementary charge; ε_0 is vacuum dielectric constant and ε_w is the water dielectric constant; C is the geometry-dependent self-capacitance²² of the pore, given by $4\varepsilon_{\rm w}\varepsilon_0\pi r^2/L$; z is the ion valence number; r is the radius of the pore and L is its length. This model highlights two important contributions that lead to ionic Coulomb blockade: a geometry-dependent self-capacitance similar to electronic Coulomb blockade and an ion valence which is unique in ionic transport. Given the verified thickness of MoS₂ nanopores and a 0.6-nm pore diameter, a Coulomb energy of about $3k_BT$ for a 0.65-nm theoretical single-layer thickness and $5 k_B T$ for a 1.6-nm hydration thickness¹² can be estimated for monovalent ions. For divalent ions, these values rise considerably to $12 k_B T$ and $20 k_B T$. A detailed estimation of the Coulomb gap for various pore diameters is given in Supplementary Table 1. The pore capacitance can also be extracted from the currentmolarity relation⁶. A non-monotonic current-molarity relation is observed, as a direct result of the capacitance effect of the pore⁶. By fitting to the classical ionic Coulomb blockade model⁶ using our device geometry and experimental results presented in Fig. 2, we obtain a pore capacitance of about 0.2 aF for the 0.6-nm pore, which is very close to our estimate, as shown in Supplementary Fig. 3. This non-monotonic behaviour is also predicted where the self-energy barrier versus concentration also shows a characteristic sharp dip in the vicinity of a certain negative monovalent dopant concentration, explained as a transition between different states²³. The second effect that contributes directly to the observed energy gap is the dehydration of ions in nanopores smaller than 0.8 nm. This contribution becomes significantly large, and a stepwise free energy barrier originating from successive breaking of the third, second and first hydration shells is introduced when reducing the pore size from 0.8 nm to zero⁷. Therefore, the dehydration effect should also be incorporated in the energy gap. To this end, we again used an analogy to the combined gap in the single-molecule system and in the ionic case; the 'energy-level spacing' is treated using the hydration energy. The estimated contribution from the ionic Coulomb blockade effect and the dehydration effect is shown in Supplementary Table 1 and Supplementary Fig. 4, and the Coulomb energy is found to be the main contribution in the pore size range 0.6 to 1 nm. In Supplementary Fig. 4, we hypothesize a transition of the role from dehydration (<0.5 nm) to ion Coulomb blockade (in the range in which we work, 0.6 to 1 nm). The single-particle dehydration effect is thus easily incorporated in the standard model of Coulomb blockade.

LETTERS

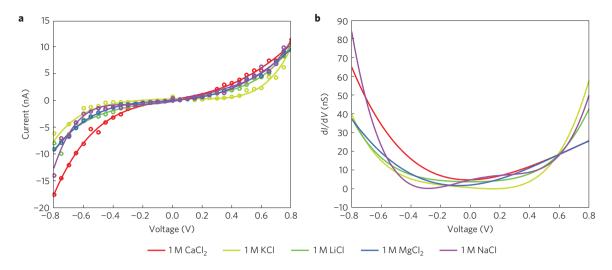


Figure 3 | Valence-dependent ion transport. a, I-V curves of a 0.6-nm MoS₂ pore acquired in different salt solutions (K⁺, Na⁺, Li⁺, Ca²⁺, Mg²⁺). **b**, Corresponding differential conductance dI/dV plots. Mg²⁺ and Ca²⁺ have a more suppressed current for positive voltages.

This charging energy is much larger than the thermal energy at room temperature (k_BT , 298 K), allowing the direct observation of Coulomb blockade in ionic transport at room temperature. An applied bias (eV) can adjust the chemical potential of the electrode, so as to add or remove a single charge carrier from the pore. When this energy rises above the Coulomb gap, the ion flux is able to pass through the pore. Measured values are in good agreement with the results from the calculations outlined above. A small deviation can be expected, due to the overestimation of the pore size and the additional capacitance between the pore and electrode. The valence dependence, where divalent ions show a slightly larger gap in the positive voltage direction than monovalent ions, is a direct consequence of the stronger Coulomb interaction between divalent ions, as shown in Fig. 3. This suppression is much lower than the straightforward estimation, and we believe that it is due to the combined result of the gap from both divalent cations (Mg^{2+}/Ca^{2+}) and monovalent anions (Cl^-). The observed I-V rectification might originate from the dipolar nature of MgCl₂/CaCl₂ due to the difference between the transport barrier for divalent cations and monovalent anions. In addition, a similar phenomenon where the self-energy barrier of CaCl₂ exhibits the same barrier as Na⁺ is also theoretically predicted, and explained by the fractionalization divalent (Mg^{2+}/Ca^{2+}) on two unit-charge cations mobile solitons²³.

To observe Coulomb oscillations in most traditional electrical devices²⁰, one would need to incorporate a voltage gate. Nevertheless, integration of the voltage gate in the atomically thick pore requires passivation with a thick layer of dielectric to reduce current crosstalk24. In turn, this requirement would compromise the atomic dimensions of our present nanofluidic device. Alternatively, in nanofluidic devices, gating can be realized by using the pH to modulate the surface charge of the system²⁵. The surface chemistry of the MoS₂ nanopore determines the negatively charged surface and an increase in pH will lead to the addition of negative charges. The ionic transport can then be modulated by the surface charge. Figure 4a shows the pH (2.5 to 11) dependence of conduction in our system. A non-monotonic dependence of pore conductance on pH is observed, and conduction peaks are found close to pH 3.5 and pH 6, which correspond to a certain integral number of excess charges in the pore, determined by the surface chemistry. However, the various possibilities of pore chemistry at the single-atom level¹⁴ can lead to variations in the conduction peaks from pore to pore, as shown in Supplementary Fig. 5. Kaufman et al.8 also modelled pore-charge-induced

Coulomb blockade oscillations by approximating the self-energy, $U_n = Q_n^2/2C$, of excess charge (where Q_n represents the excess charge at the pore for the n ions as a function of Q_f , $Q_n = zen + Q_f$) and applying Fermi–Dirac occupancy statistics. The blockade region is found around a neutralized excess charge, and barrier-less conduction appears at the crossover point where $U_n = U_{n+1}$, which corresponds to the conductance oscillations we observed at certain pH values.

The Coulomb gap of the single-ion channel can be further engineered by adjusting the pore size. In the absence of the pore, the defect-free membrane is almost insulating, and the leakage current is very low (pA range). The smallest nanopore from a single vacancy with either two sulfur atoms or one molybdenum atom missing would produce a large gap, providing this structure is thermodynamically stable in liquid²⁶. Single vacancies can also be generated using our controlled electrochemical pore fabrication method. However, it is difficult to measure the gap of a single vacancy (d < 3 Å) in practice because a bias voltage higher than 0.8 V can result in the electrochemical dissolution of MoS₂. We find only a handful of freestanding, defect-free MoS₂ membranes suspended over small windows (<50 nm) that can operate up to 5 V. Supplementary Fig. 6 gives an example of an I-V measurement performed on a 0.3-nm pore. A larger gap of ~1.2 V is observed, and the voltage is swept in both directions. Cyclic I-V measurements are taken to prevent the enlargement of the existing pore or the formation of a new pore in the presence of a high bias. We suspect the dehydration of a strong second hydration shell also plays an important role here. The measured gap size decreases with increasing pore size, and the charging energy can be obtained directly from the gap. As shown in Fig. 4c-e, a linear transition point is found near 1 nm, indicating the disappearance of the transport barrier, with the I-V characteristic becoming linear after this point. The strong correlation between the nonlinearity of the currentvoltage characteristics and the pore dimension further confirms that ionic Coulomb blockade is at the origin of the observed effect. With larger pores, the weak Coulomb interaction could in principle be measured at low temperatures, and even Coulomb stairs might be observed at low voltages. However, operation at low temperatures is limited by the liquid environment itself. Single-step transition from an insulating regime dominated by Coulomb blockade to a semiconducting regime has been observed previously in metallic quantum dots^{27,28}.

The prediction of ion transport through a symmetric biological ion channel has shown Coulomb blockade with a very similar

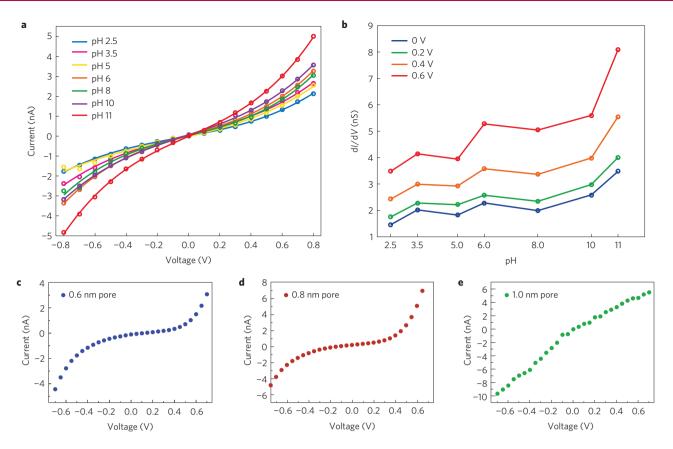


Figure 4 | pH-induced conductance oscillations. \mathbf{a} , pH-gated ionic transport through a 0.8-nm MoS₂ nanopore. I-V curves are taken in various pH conditions of 1 M KCl (pH 2.5 to 11). \mathbf{b} , dI/dV curves acquired in various pH conditions of 1 M KCl (pH 2.5 to 11). The differential conductance exhibits a non-monotonic behaviour with pH (surface charge). \mathbf{c} - \mathbf{e} , Variation of the linear-nonlinear transition with changing pore size, 0.6 nm (\mathbf{c}), 0.8 nm (\mathbf{d}) and 1 nm (\mathbf{e}). The gap size decreases with the pore size, and disappears when the pore size reaches 1 nm.

geometry, pore size of 0.6 nm and thickness of 1.6 nm (ref. 8). The good agreement between the above prediction and experimental results further strengthens our claims. Finally, although Coulomb blockade⁸ (a many-body effect) is concomitant with the single-particle dehydration effect⁷, the following four observations support the contribution from Coulomb blockade: the low capacitance of the experimental configuration, the valence dependence, the peaks in current–molarity relation, and the conductance oscillations from pH-induced surface charge modulation (Supplementary Information, Coulomb blockade discussion).

The observation of unique ionic transport in sub-nm pores is, to our knowledge, the first instance of a quantum-like mesoscopic effect dominating ionic transport. The measured nonlinear currentvoltage dependence for individual sub-nm pores is a consequence of single-ion charging behaviour, as described by the ionic Coulomb blockade model8. Other possibilities that may also introduce a transport barrier, such as a dehydration effect, could also be further incorporated in the standard model. Our findings can be applied to nanopores with similar geometries. Our measurements provide direct experimental evidence that the effects observed here should also play a role in the functioning of biological ion channels, such as voltage-gated ion channels, as suggested in the theoretical model proposed by Kaufman and colleagues8. Future experiments investigating various gating effects, combined with better theoretical modelling, are needed to elucidate the results reported here. The blockade region also adds a new dimension to practical applications, such as water desalination²⁹. We believe that atomically thin and small (<1 nm) pores offer a new platform from which to explore novel physics in the research areas of both nanoscale fluidics and biology.

Methods

Methods and any associated references are available in the online version of the paper.

Received 23 September 2015; accepted 24 February 2016; published online 28 March 2016

References

- Datta, S. Electronic Transport in Mesoscopic Systems (Cambridge Univ. Press, 1997).
- Perrin, M. L., Burzuri, E. & van der Zant, H. S. J. Single-molecule transistors. Chem. Soc. Rev. 44, 902–919 (2015).
- Aviram, A. & Ratner, M. A. Molecular rectifiers. Chem. Phys. Lett. 29, 277–283 (1974).
- Nitzan, A. & Ratner, M. A. Electron transport in molecular wire junctions. Science 300, 1384–1389 (2003).
- Park, J. et al. Coulomb blockade and the Kondo effect in single-atom transistors. Nature 417, 722–725 (2002).
- Krems, M. & Di Ventra, M. Ionic coulomb blockade in nanopores. J. Phys. Condens. Matter 25, 065101 (2013).
- Zwolak, M., Lagerqvist, J. & Di Ventra, M. Quantized ionic conductance in nanopores. *Phys. Rev. Lett.* 103, 128102 (2009).
- Kaufman, I. K., McClintock, P. & Eisenberg, R. Coulomb blockade model of permeation and selectivity in biological ion channels. *New J. Phys.* 17, 083021 (2015).
- Sparreboom, W., van den Berg, A. & Eijkel, J. C. T. Principles and applications of nanofluidic transport. *Nature Nanotech.* 4, 713–720 (2009).
- Powell, M. R., Cleary, L., Davenport, M., Shea, K. J. & Siwy, Z. S. Electric-field-induced wetting and dewetting in single hydrophobic nanopores. *Nature Nanotech.* 6, 798–802 (2011).
- Jain, T. et al. Heterogeneous sub-continuum ionic transport in statistically isolated graphene nanopores. Nature Nanotech. 10, 1053–1057 (2015).

LETTERS NATURE MATERIALS DOI: 10.1038/NMAT4607

- Liu, K., Feng, J. D., Kis, A. & Radenovic, A. Atomically thin molybdenum disulfide nanopores with high sensitivity for DNA translocation. ACS Nano 8, 2504–2511 (2014).
- 13. Feng, J. et al. Electrochemical reaction in single layer MoS₂: nanopores opened atom by atom. *Nano Lett.* **15**, 3431–3438 (2015).
- Farimani, A. B., Min, K. & Aluru, N. R. DNA base detection using a single-layer MoS₂. ACS Nano 8, 7914–7922 (2014).
- Ho, C. et al. Electrolytic transport through a synthetic nanometer-diameter pore. Proc. Natl Acad. Sci. USA 102, 10445–10450 (2005).
- Cervera, J., Schiedt, B. & Ramirez, P. A Poisson/Nernst-Planck model for ionic transport through synthetic conical nanopores. *Europhys. Lett.* 71, 35–41 (2005).
- 17. Radenovic, A., Trepagnier, E., Csencsits, R., Downing, K. H. & Liphardt, J. Fabrication of 10 nm diameter hydrocarbon nanopores. *Appl. Phys. Lett.* **93**, 183101 (2008).
- 18. Beenakker, C. W. J. Theory of Coulomb-blockade oscillations in the conductance of a quantum dot. *Phys. Rev. B* 44, 1646–1656 (1991).
- Fulton, T. A. & Dolan, G. J. Observation of single-electron charging effects in small tunnel-junctions. *Phys. Rev. Lett.* 59, 109–112 (1987).
- Kouwenhoven, L. P. et al. in Mesoscopic Electron Transport (eds Sohn, L. L., Kouwenhoven, L. P. & Schön, G.) 105–214 (Kluwer, 1997).
- Parsegian, A. Energy of an ion crossing a low dielectric membrane: solutions to four relevant electrostatic problems. *Nature* 221, 844–846 (1969).
- Zhang, J., Kamenev, A. & Shklovskii, B. I. Conductance of ion channels and nanopores with charged walls: a toy model. *Phys. Rev. Lett.* 95, 148101 (2005).
- 23. Zhang, J., Kamenev, A. & Shklovskii, B. Ion exchange phase transitions in water-filled channels with charged walls. *Phys. Rev. E* **73**, 051205 (2006).
- Traversi, F. et al. Detecting the translocation of DNA through a nanopore using graphene nanoribbons. Nature Nanotech. 8, 939–945 (2013).
- 25. Štein, D., Kruithof, M. & Dekker, C. Surface-charge-governed ion transport in nanofluidic channels. *Phys. Rev. Lett.* **93**, 035901 (2004).

- Lee, J. et al. Stabilization of graphene nanopore. Proc. Natl Acad. Sci. USA 111, 7522–7526 (2014).
- Hong, I.-P., Brun, C., Pivetta, M., Patthey, F. & Schneider, W.-D. Coulomb blockade phenomena observed in supported metallic nanoislands. *Front. Phys.* 1, 13 (2013)
- Romero, H. E. & Drndic, M. Coulomb blockade and hopping conduction in PbSe quantum dots. *Phys. Rev. Lett.* 95, 156801 (2005).
- Heiranian, M., Farimani, A. B. & Aluru, N. R. Water desalination with a single-layer MoS₂ nanopore. *Nature Commun.* 6, 8616 (2015).

Acknowledgements

This work was financially supported by the European Research Council (grant no. 259398, PorABEL), SNSF Consolidator grant (BIONIC BSCGI0_157802) and SNSF Sinergia Grant no. 147607. We thank the Centre Interdisciplinaire de Microscopie Électronique (CIME) at EPFL for access to electron microscopes and D. Alexander for help with Cs-corrected TEM (Titan Themis). We thank S. Marion and P. Leburton for their careful reading of our manuscript and for the helpful comments. Device fabrication was partially carried out at the EPFL Center for Micro/Nanotechnology (CMi).

Author contributions

J.F. conceived the idea, performed the measurements and interpreted the results. J.F. and K.L. fabricated the devices. J.F. and M.G. performed data analysis. D.D. and A.K. provided CVD-grown MoS_2 samples. M.D.V. proposed the current–molarity relation. J.F. and A.R. designed the experiments and wrote the manuscript. A.R. supervised the work. All authors commented on the manuscript.

Additional information

Supplementary information is available in the online version of the paper. Reprints and permissions information is available online at www.nature.com/reprints.

Correspondence and requests for materials should be addressed to J.F. or A.R.

Competing financial interests

The authors declare no competing financial interests.

NATURE MATERIALS DOI: 10.1038/NMAT4607 LETTERS

Methods

Nanopore fabrication. The MoS $_2$ nanopores are fabricated either using our recently reported atomic-scale nanopore fabrication technique based on controlled electrochemical reaction (ECR; ref. 13) or using electron irradiation 12 . Briefly, SiN $_x$ membranes (10 μ m \times 10 μ m to 50 μ m \times 50 μ m, 20 nm thick) are manufactured using KOH wet etching. Focused ion beam (FIB) irradiation is applied to drill a 50–300-nm opening on that membrane. CVD-grown single-layer MoS $_2$ (ref. 30) membranes are suspended on the FIB opening by transferring from sapphire substrates using a MoS $_2$ transfer stage. ECR is done by applying a step-like transmembrane potential to the membrane and monitoring the transmembrane ionic current with a FEMTO DLPCA-200 amplifier (FEMTO Messtechnik GmbH). Nanopores are formed under the critical voltage (>0.8 V). The size estimation has an error bar of 0.1 nm with aberration-corrected TEM images and 0.2 nm with ECR pore formation 13 .

Ionic transport measurement. Ionic transport experiments are performed using the same set-up as described before ^{12,13}. After mounting in the polymethylmethacrylate (PMMA) chamber, the chips were wetted with

 $\rm H_2O$:
ethanol (1:1) for (30 min–24 h to rule out hydrophobic effects). Ionic transport is performed by taking the current–voltage response (I-V characteristic) of the nanopore in salty solutions (various ion types, ionic concentration or pH) using an Axopatch 200B patch clamp amplifier (Molecular Devices) or a FEMTO DLPCA-200 amplifier for a higher bias than 1 V. A pair of chlorinated Ag/AgCl electrodes is used to apply the voltage and detect the current. Current–voltage measurements (I-V characteristic) are performed by applying an alternating voltage sweep with a step size from 10 to 50 mV and measuring the current (recording frequency 6,250 Hz) at same time. The current at each voltage value is measured for 10 s and the voltage range is typically set to -800 to 800 mV. The I-V curve is then plotted using the voltage values and corresponding fitted steady-state current. The measured error bar is below 1% and therefore not plotted. Crosscheck experiments have been done to make sure the pore is not enlarged.

References

 Dumcenco, D. et al. Large-area epitaxial monolayer MoS₂. ACS Nano 9, 4611–4620 (2015).